

# PC3H41x NIP Series PC3Q410 NIP

## ■ Features

1. Low input current type ( $I_F = \pm 0.5\text{mA}$ )
2. High resistance to noise due to high common rejection voltage (CMR:MIN. 10kV/ $\mu\text{s}$ )
3. AC input type
4. Mini-flat package **PC3H41x NIP Series** (1ch)  
**PC3Q410 NIP** (4ch)
5. Isolation voltage ( $V_{iso}$ :2.5kVrms)
6. Recognized by UL, file No. E64380

## ■ Applications

1. Programmable controllers
2. Facsimiles
3. Telephones

## ■ Rank Table

| Model No.         | Rank mark    | $I_c$ (mA)  | Conditions   |
|-------------------|--------------|-------------|--|
| <b>PC3H410NIP</b> | A or no mark | 0.25 to 2.0 | $I_F = \pm 0.5\text{mA}$<br>$V_{CE} = 5\text{V}$<br>$T_a = 25^\circ\text{C}$ |
| <b>PC3H411NIP</b> | A            | 0.5 to 1.5  |  |
| Model No.         | Rank mark    | $I_c$ (mA)  | Conditions   |
| <b>PC3Q410NIP</b> | No mark      | 0.25 to 2.0 | $I_F = \pm 0.5\text{mA}$<br>$V_{CE} = 5\text{V}$<br>$T_a = 25^\circ\text{C}$ |

## ■ Absolute Maximum Ratings (Ta=25°C)

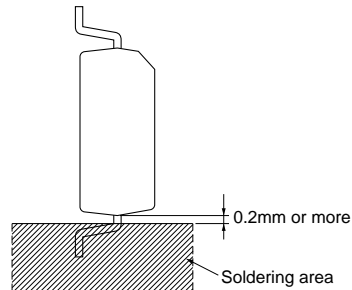
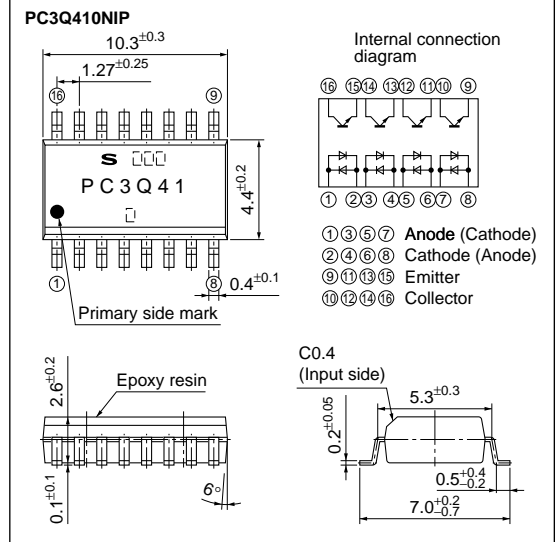
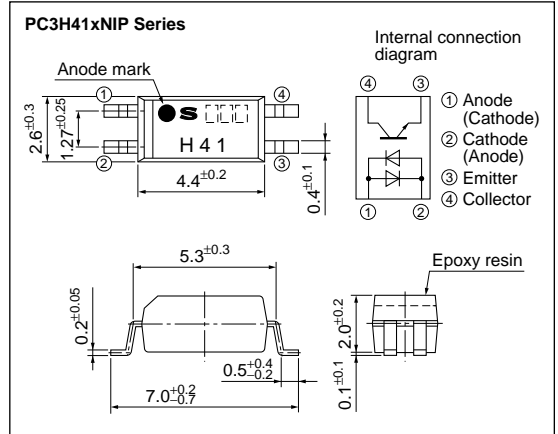
| Parameter                |                             | Symbol    | Rating      | Unit  |
|--------------------------|-----------------------------|-----------|-------------|-------|
| Input                    | Forward current             | $I_F$     | $\pm 10$    | mA    |
|                          | *1 Peak forward current     | $I_{FM}$  | $\pm 200$   | mA    |
|                          | Power dissipation           | P         | 15          | mW    |
| Output                   | Collector-emitter voltage   | $V_{CEO}$ | 70          | V     |
|                          | Emitter-collector voltage   | $V_{ECO}$ | 6           | V     |
|                          | Collector current           | $I_c$     | 50          | mA    |
|                          | Collector power dissipation | $P_c$     | 150         | mW    |
|                          | Total power dissipation     | $P_{tot}$ | 170         | mW    |
| Operating temperature    |                             | $T_{opr}$ | -30 to +100 | °C    |
| Storage temperature      |                             | $T_{stg}$ | -40 to +125 | °C    |
| *2 Isolation voltage     |                             | $V_{iso}$ | 2.5         | kVrms |
| *3 Soldering temperature |                             | $T_{sol}$ | 260         | °C    |

\*1 Pulse width  $\leq 100\mu\text{s}$ , Duty ratio = 0.001  
 \*2 40 to 60%RH, AC for 1 minute,  $f = 60\text{Hz}$   
 \*3 For 10s

## AC Input, Low Input Current Type Photocoupler

## ■ Outline Dimensions

(Unit : mm)



■ Electro-optical Characteristics

(Ta=25°C)

| Parameter                |                                      | Symbol        | Conditions                                   | MIN.   | TYP.      | MAX. | Unit     |                   |
|--------------------------|--------------------------------------|---------------|--|--|-----------|------|----------|-------------------|
| Input                    | Forward voltage                      | $V_F$         | $I_F = \pm 10\text{mA}$                      | —  | 1.2       | 1.4  | V        |                   |
|                          | Terminal capacitance                 | $C_t$         | $V = 0, f = 1\text{kHz}$                     | —  | 30        | 250  | pF       |                   |
| Output                   | Collector dark current               | $I_{CEO}$     | $V_{CE} = 50\text{V}, I_F = 0$               | —  | —         | 100  | nA       |                   |
|                          | Collector-emitter breakdown voltage  | $BV_{CEO}$    | $I_C = 0.1\text{mA}, I_F = 0$                | 70   | —         | —    | V        |                   |
|                          | Emitter-collector breakdown voltage  | $BV_{ECO}$    | $I_E = 10\mu\text{A}, I_F = 0$               | 6  | —         | —    | V        |                   |
| Transfer characteristics | Collector current                    | $I_C$         | $I_F = \pm 0.5\text{mA}, V_{CE} = 5\text{V}$ | 0.25   | —         | 2.0  | mA       |                   |
|                          | Collector-emitter saturation voltage | $V_{CE(sat)}$ | $I_F = \pm 10\text{mA}, I_C = 1\text{mA}$    | —  | —         | 0.2  | V        |                   |
|                          | Isolation resistance                 | $R_{ISO}$     | DC500V 40 to 60%RH                           | $5 \times 10^{10}$   | $10^{11}$ | —    | $\Omega$ |                   |
|                          | Floating capacitance                 | $C_f$         | $V = 0, f = 1\text{MHz}$                     | —  | 0.6       | 1.0  | pF       |                   |
|                          | Response time                        | Rise time     | $t_r$  | $V_{CE} = 2\text{V}, I_C = 2\text{mA}, R_L = 100\Omega$  | —         | 4    | 18       | $\mu\text{s}$     |
|                          |                                      | Fall time     | $t_f$  |  | —         | 3    | 18       | $\mu\text{s}$     |
|                          | *1 Common mode rejection voltage     |               | CMR  | $T_a = 25^\circ\text{C}, R_L = 470\Omega, V_{CM} = 1.5\text{kV (peak)}, I_F = 0\text{mA}, V_{CC} = 9\text{V}, V_{np} = 100\text{mV}$ | 10        | —    | —        | kV/ $\mu\text{s}$ |

\*1 Refer to Fig.1.

Fig.1 Test Circuit for Common Mode Rejection Voltage

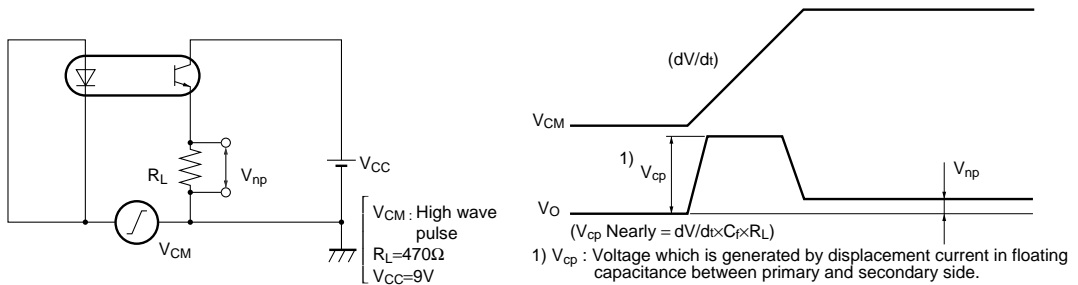


Fig.2 Forward Current vs. Ambient Temperature

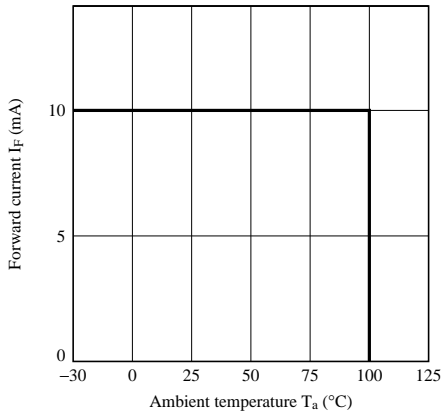
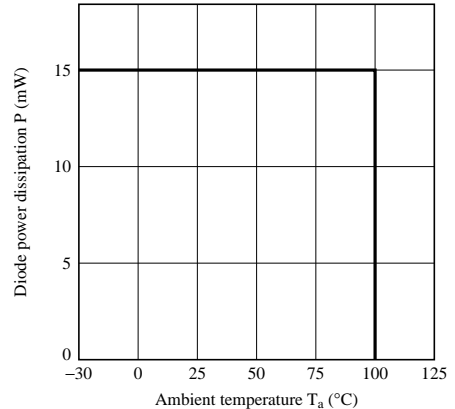
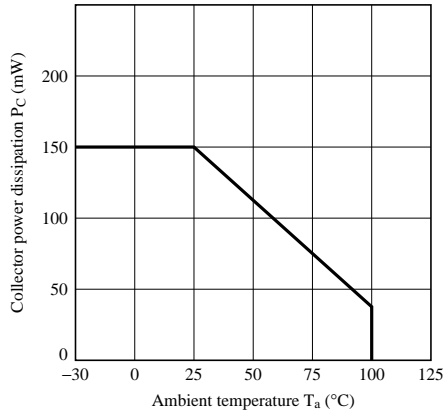


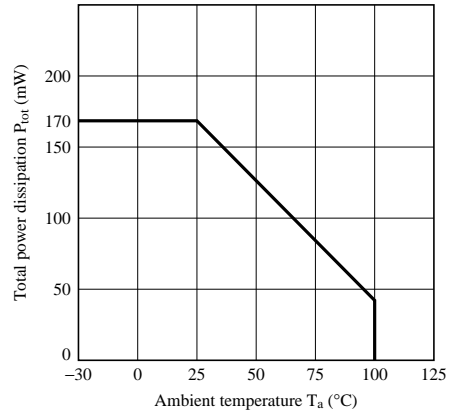
Fig.3 Diode Power Dissipation vs. Ambient Temperature



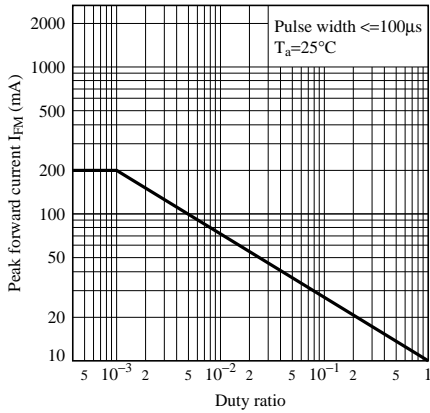
**Fig.4 Collector Power Dissipation vs. Ambient Temperature**



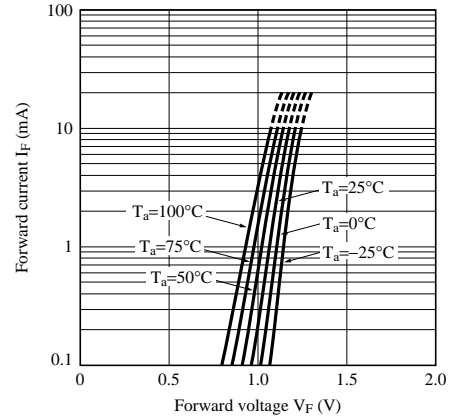
**Fig.5 Total Power Dissipation vs. Ambient Temperature**



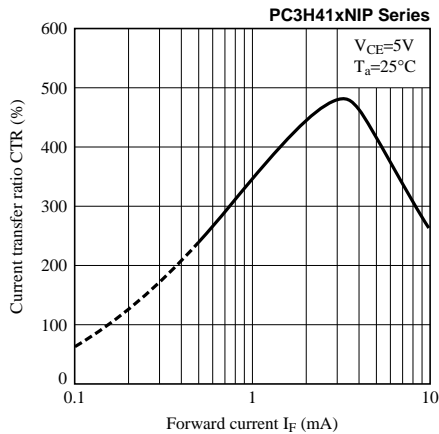
**Fig.6 Peak Forward Current vs. Duty Ratio**



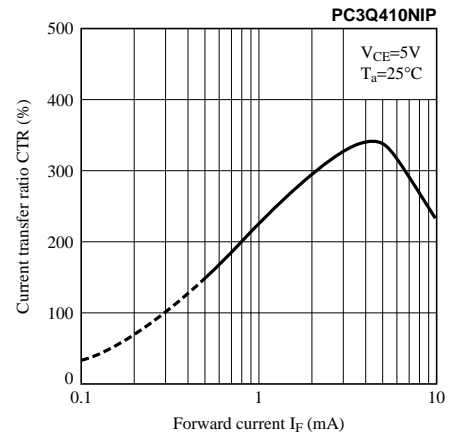
**Fig.7 Forward Current vs. Forward Voltage**



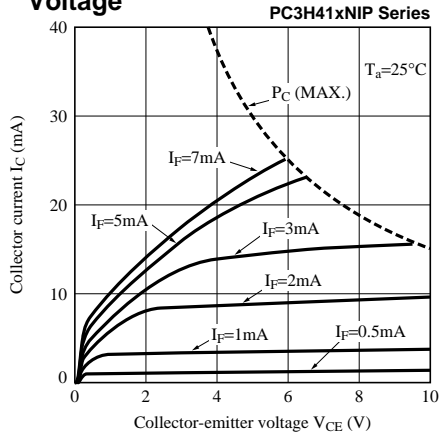
**Fig.8 Current Transfer Ratio vs. Forward Current**



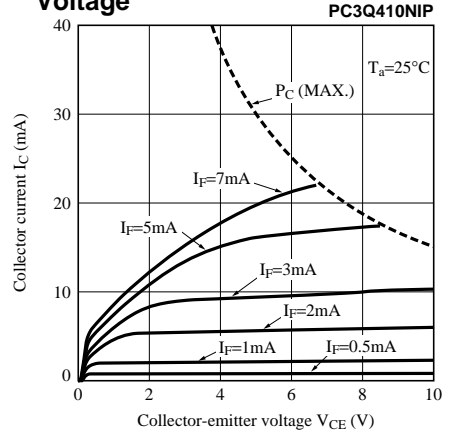
**Fig.9 Current Transfer Ratio vs. Forward Current**



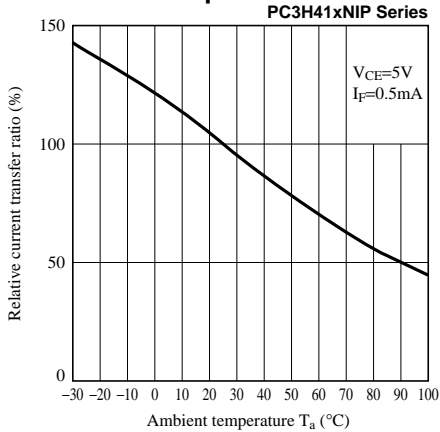
**Fig.10 Collector Current vs. Collector-emitter Voltage**



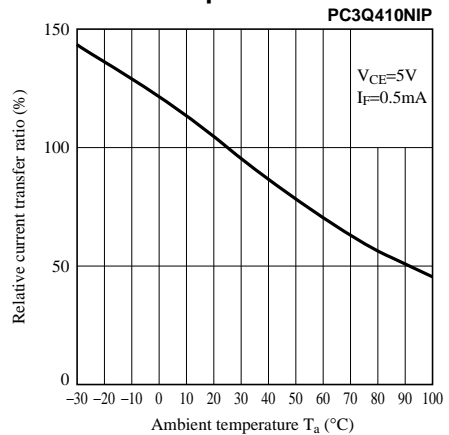
**Fig.11 Collector Current vs. Collector-emitter Voltage**



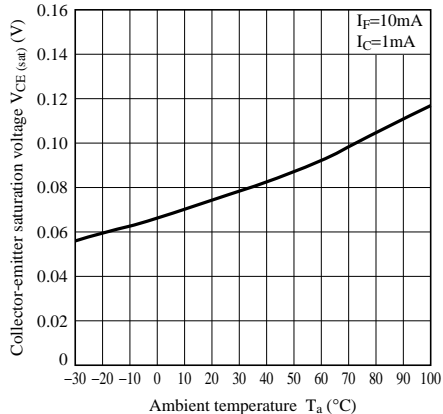
**Fig.12 Relative Current Transfer Ratio vs. Ambient Temperature**



**Fig.13 Relative Current Transfer Ratio vs. Ambient Temperature**



**Fig.14 Collector - emitter Saturation Voltage vs. Ambient Temperature**



**Fig.15 Collector Dark Current vs. Ambient Temperature**

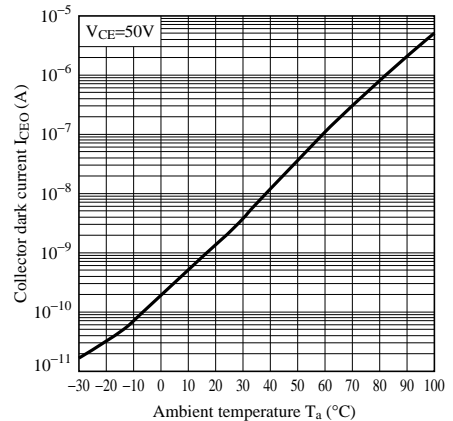


Fig.16 Response Time vs. Load Resistance

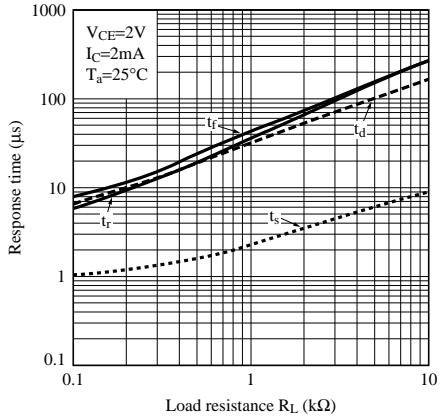


Fig.17 Response Time vs. Load Resistance (Saturation)

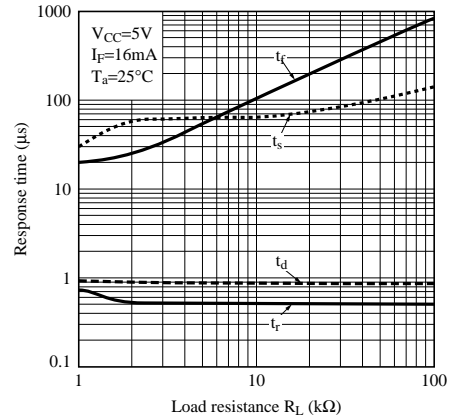


Fig.18 Test Circuit for Response Time

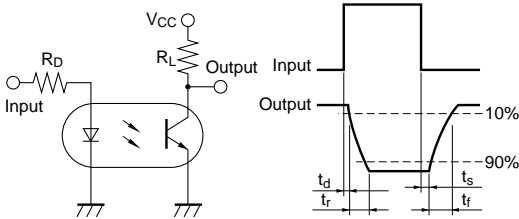


Fig.19 Voltage Gain vs Frequency

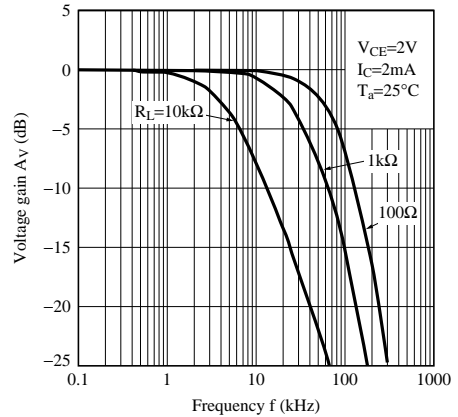


Fig.20 Collector-emitter Saturation Voltage vs. Forward Current

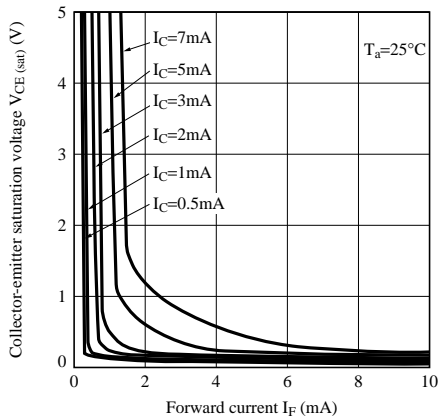


Fig.21 Reflow Soldering

Only one time soldering is recommended within the temperature profile shown below.

